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WHAT IS CLAIMED IS:

- 1. A semiconductor device comprising:
- a substrate;
- a semiconductor chip arranged on the substrate;
- a first electrode formed in the substrate and connected to the semiconductor chip;
 - a concave portion provided on a side of the substrate, the concave portion extending from a back of the substrate and terminating in the substrate, and at least part of the first electrode being exposed to the concave portion; and
 - a metal layer formed on the at least part of the first electrode.
 - 2. The semiconductor device according to claim 1, wherein the metal layer is short of the side of the substrate.
 - 3. The semiconductor device according to claim 1, wherein the substrate is a multilayer substrate including at least two layers.
 - 4. The semiconductor device according to claim 3, wherein the concave portion is provided in a layer other than an uppermost layer of the multilayer substrate.
- 5. The semiconductor device according to claim 3,
 wherein the concave portion is provided in a layer
 other than a multilayer including an uppermost layer of
 the multilayer substrate.

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- 6. The semiconductor device according to claim 3, wherein the concave portion is provided in a lowermost layer of the multilayer substrate.
- 7. The semiconductor device according to claim 3, wherein the concave portion is provided in a multilayer including a lowermost layer of the multilayer substrate and excluding an uppermost layer of the multilayer substrate.
- 8. The semiconductor device according to claim 1, wherein the semiconductor chip comprises an active element.
- 9. The semiconductor device according to claim 1, wherein the semiconductor chip comprises an active element and a passive element.
- 10. The semiconductor device according to claim 1, further comprising sealing resin formed on the substrate, the semiconductor chip, and the first electrode.
- 11. The semiconductor device according to claim 10, wherein the sealing resin includes a magnetic substance.
 - 12. The semiconductor device according to claim 1, further comprising a second electrode formed in the substrate separately from the first electrode, and the semiconductor chip being arranged on a top of the second electrode.
 - 13. The semiconductor device according to claim 1,

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wherein the semiconductor chip and the first electrode are connected to each other through a bonding wire.

- 14. The semiconductor device according to claim 1, wherein the concave portion is one of a quadrilateral and a semicircle.
- 15. The semiconductor device according to claim 1, which comprises a leadless package structure.